# 3422

## PRELIMINARY INFORMATION (subject to change without notice) Februaryt 21, 2003



Pinning is shown viewed from branded side.

#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage, $V_{CC}$ 18 V
Magnetic Flux Density, B Unlimited
Output OFF Voltage, $V_{OUT}$ $V_{CC}$
Output Sink Current, $I_{OUT}$ 30 mA
Package Power Dissipation,
$P_D$ 500 mW
Operating Temperature Range, T <sub>A</sub>
Suffix 'E–'40°C to +85°C
Suffix 'L-'40°C to +150°C
Storage Temperature Range,
T <sub>S</sub>

# HALL-EFFECT, DIRECTION-DETECTION SENSORS

The A3422xKA Hall-effect, direction-detection sensor is a new generation of special-function integrated sensors that is capable of sensing the direction of rotation of a ring magnet. This transducer provides separate digital outputs that provide information on magnet rotation speed, direction, and magnet pole count. This device eliminates the major manufacturing hurdles encountered in fine-pitch direction-detection applications, namely maintaining accurate mechanical location between the two active Hall elements. Here, the two Hall elements are photolithographically aligned to better than 1  $\mu$ m, as contrasted with 100  $\mu$ m or worse mechanical location tolerance when manufactured discretely. This highly sensitive, temperature-stable, magnetic transducer is ideal for use in digital-encoder systems in the harsh environments of automotive or industrial applications. The A3422xKA is a high-sensitivity device optimized for use with high-density magnets.

The A3422xKA monolithic integrated circuit contains two independent Hall-effect latches whose digital outputs are internally coupled to CMOS logic circuitry that decodes signal speed and direction. Extremely low-drift BiCMOS circuitry is used for the amplifiers to ensure symmetry between the two latches so that signal quadrature can be maintained. An on-chip voltage regulator allows the use of this device from a 4.5 V to 18 V supply. The outputs are standard open-collector outputs.

Two operating temperature ranges are provided; suffix 'E-' is for the automotive and industrial temperature range of  $-40^{\circ}$ C to  $+85^{\circ}$ C, suffix 'L-' is for the automotive and military temperature range of  $-40^{\circ}$ C to  $+150^{\circ}$ C. The 5-pin 'KA' SIP package provides a costcompetitive solution to magnetic sensing in harsh environments.

#### FEATURES

- Internal Direction-Decoding Circuitry
- Two Matched Hall Latches On A Single Substrate
- Superior Temperature Stability
- 4.5 V to 18 V Operation Electrically Defined Power-On State Under-Voltage Lockout

Always order by complete part number: the prefix 'A' + the basic fourdigit part number + a suffix to indicate operating temperature range + a suffix to indicate package style, e.g.,  $\boxed{A3422EKA}$ .





FUNCTIONAL BLOCK DIAGRAM

Dwg. WH-012A



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			Limits			
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Supply Voltage Range	V <sub>cc</sub>	Operating, T <sub>J</sub> < 165°C <sup>1</sup>	4.5	_	18	V
Output Leakage Current	I <sub>OFF</sub>	V <sub>OUT</sub> = V <sub>CC</sub> = 18 V	_	<1.0	10	μΑ
Output Saturation Voltage	V <sub>OUT(SAT)</sub>	I <sub>OUT</sub> = 20 mA	_	0.21	0.50	V
Power-On State	POS	$V_{CC} = 0 \rightarrow 5 V$ , $B_{RP1} < B < B_{OP1}$ , $B_{RP2} < B < B_{OP2}$	OFF	OFF	OFF	—
Under-Voltage Lockout	V <sub>CC(UV)</sub>	$I_{OUT}$ = 20 mA, $V_{CC}$ = 0 $\rightarrow$ 5 V	_	3.5	_	V
Under-Voltage Hysteresis	V <sub>CC(hys)</sub>	Lockout ( $V_{CC(UV)}$ ) - Shutdown	_	0.5	_	V
Power-On Time	t <sub>po</sub>	V <sub>CC</sub> > 4.5 V	_	_	50	μs
Output Rise Time	t <sub>r</sub>	$C_L$ = 20 pF, $R_L$ = 820 $\Omega$	_	200	_	ns
Output Fall Time	t <sub>f</sub>	$C_L$ = 20 pF, $R_L$ = 820 $\Omega$	_	200	_	ns
Direction Change Delay	t <sub>d</sub>	$C_{L} = 20 \text{ pF}, R_{L} = 820 \Omega$	0.5	1.0	5.0	μs
Supply Current	I <sub>cc</sub>	V <sub>CC</sub> = 8 V, All outputs OFF	5.0	9.0	18	mA

#### ELECTRICAL CHARACTERISTICS over operating temperature range.

NOTES:1. Maximum supply voltage must be adjusted for power dissipation and ambient temperature.

2. Typical Data is at  $V_{CC} = 12$  V and  $T_A = +25^{\circ}C$  and is for design information only.



#### MAGNETIC CHARACTERISTICS over operating voltage range.

			Limits			
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Operate Point	B <sub>OP</sub>	T <sub>A</sub> = -40°C	_	—	85	G
		T <sub>A</sub> = +25°C	_	29	75	G
		T <sub>A</sub> = Maximum	_		75	G
Release Point <sup>3</sup>	B <sub>RP</sub>	T <sub>A</sub> = -40°C	-85	_		G
		T <sub>A</sub> = +25°C	-75	-17	—	G
		T <sub>A</sub> = Maximum	-75	—	_	G
Hysteresis	B <sub>hys</sub>	T <sub>A</sub> = -40°C	10	—	_	G
		T <sub>A</sub> = +25°C	10	46	_	G
		T <sub>A</sub> = Maximum	10			G
Operate Differential		B <sub>OP1</sub> - B <sub>OP2</sub>			±60	G
Release Differential		B <sub>RP1</sub> - B <sub>RP2</sub>	_		±60	G

NOTES: 1. Magnetic flux density is measured at most sensitive area of device,

- nominally located 0.0165" (0.42 mm) below the branded face of the package.
- 2. Typical Data is at  $V_{CC} = 12$  V and  $T_A = +25^{\circ}C$  and is for design information only.
- 3. As used here, negative flux densities are defined as less than zero (algebraic convention).

### **Typical Magnetic Characteristics**











#### **Functional Description**

The integrated circuit contains an internal voltage regulator that powers the Hall sensors and both the analog and digital circuitry. This regulator allows operation over a wide supply voltage range and provides some immunity to supply noise. The device also contains CMOS logic circuitry that decodes the direction of rotation of the ring magnet.

Quadrature/Direction Detection. Internal logic circuitry provides outputs representing speed and direction of the magnetic field across the face of the package. For the direction signal to be appropriately updated, a quadrature relationship must be maintained between the ring magnet pole width\*, the sensor-tosensor spacing, and, to a lesser extent, the magnetic switch points. For optimal design, the sensor should be actuated with a ring magnet pole width\* two times the sensor-to-sensor spacing. This will produce a sinusoidal magnetic field whose period (denoted as T) is then four times the sensor-to-sensor spacing. A quadrature relationship can also be maintained for a ring magnet that has a period that satisfies the relationship nT/4 = 1.5 mm, where n is any odd integer. Therefore, ring magnets with pole-pair spacings equal to 6 mm (n = 1), 2 mm (n = 3), 1.2 mm (n = 5), etc. are permitted.

The response of the device to the magnetic field produced by a rotating ring magnet is shown on page 2. Note the phase shift between the two integrated sensors. **Outputs.** The device provides three saturated outputs: DIRECTION, E1 OUTPUT, and SPEED. DIRECTION provides the direction output of the sensor and is defined as OFF (high) for the direction E1 to E2 and ON (low) for the direction E2 to E1. SPEED provides an XOR'd output of the two sensors. Because of internal delays, DIRECTION will always be updated before SPEED and is updated at every transition of E1 OUTPUT and E2 OUTPUT (internal) allowing the use of up-down counters without the loss of pulses.

**Power-On State.** At power on, the logic circutry is reset to provide an OFF (high) at DIRECTION and an OFF (high) for E1 and E2 (internal) for magnetic fields less than  $B_{OP}$ . This eliminates ambiguity when the device is powered up and either sensor detects a field between  $B_{OP}$  and  $B_{RP}$ . If either sensor is subjected to a field greater than  $B_{OP}$ , the internal logic will set accordingly.

\*"Pole" refers to a single pole (North or South) unless stated as "pole pair" (North <u>and</u> South).



#### **Applications Information**

#### **Operation with Fine-Pitch Ring Magnets.** For

targets with a circular pitch of less than 4mm, a performance improvement can be observed by rotating the front face of the sensor subassembly (see below). This sensor rotation decreases the effective sensor-to-sensor spacing, provided that the Hall elements are not rotated beyond the width of the target. **Applications.** It is strongly recommended that an external 0.01  $\mu$ F bypass capacitor be connected (in close proximity to the Hall sensor) between the supply and ground of the device to reduce both external noise and noise generated by the internal logic.

The simplest form of magnet that will operate these devices is a ring magnet. Other methods of operation, such as linear magnets, are possible. Extensive applications information on magnets and Hall-effect sensors is also available in the "Hall-Effect IC Applications Guide" which can be found in the latest issue of the *Allegro MicroSystems Electronic Data Book,* AMS-702 or *Application Note* 27701, or at

www.allegromicro.com



#### **Criteria for Device Qualification**

All Allegro sensors are subjected to stringent qualification requirements prior to being released to production. To become qualified, except for the destructive ESD tests, no failures are permitted.

Qualification Test	Test Method and Test Conditions	Test Length	Samples Per Lot	Comments
Temperature Humidity Bias Life	JESD22-A101, T <sub>A</sub> = 85°C, RH = 85%	1000 hrs	77	Device biased for minimum power
Bias Life	JESD22-A108, T <sub>A</sub> = 150°C, T <sub>J</sub> = 165°C	1000 hrs	77	
(Surge Operating Life)	JESD22-A108, T <sub>A</sub> = 175°C, T <sub>J</sub> = 190°C	1000 hrs	77	
Autoclave, Unbiased	JESD22-A102, T <sub>A</sub> = 121°C, 15 psig	96 hrs	77	
High-Temperature (Bake) Storage Life	JESD22-A103, T <sub>A</sub> = 170°C	1000 hrs	77	
Temperature Cycle	JESD22-A104	1000 cycles	77	-55°C to +150°C
ESD, Human Body Model	CDF-AEC-Q100-002	Pre/Post Reading	3 per test	Test to failure All leads > 5 kV
ESD, Machine Model	JESD22-A115	Pre/Post Reading	3 per test	Test to failure All leads > 500 V

Sensor Locations (±0.005" [0.13 mm] die placement)







#### Package Designator 'KA'

#### Surface-Mount Lead Form (add '-TL' to part number)



NOTES: 1. Tolerances on package height and width represent allowable mold offsets. Dimensions given are measured at the widest point (parting line).

- 2. Exact body and lead configuration at vendor's option within limits shown.
- 3. Height does not include mold gate flash.
- 4. Recommended minimum PWB hole diameter to clear transition area is 0.035" (0.89 mm).
- 5. Where no tolerance is specified, dimension is nominal.
- 6. Supplied in bulk pack (500 pieces per bag).

## HALL-EFFECT SENSORS

DUAL-OUTPUT HALL-EFFECT DIGITAL SWITCHES								
Partial Part Number	Operate Point (G) Over Oper	Release Point (G) . Voltage & Ter	Hysteresis (G) np. Range	Oper. Temp.	Package	Comments		
UGN3235 UGN3275	35 to 200 -200 to -35 15 to 250	15 to 190 -190 to -15 -250 to -15	15 to 110 15 to 110 >100	S S	K K	independent switch outputs complementary latch outputs		
	DIRECTION-DETECTING HALL-EFFECT DIGITAL SWITCHES							
Partial Part Number	Operate Point (G) Over Oper	Release Point (G) . Voltage & Ter	Hysteresis (G) np. Range	Oper. Temp.	Package	Comments		
A3422x A3425L	<85 <30	>-85 >-30	>10 5 to 35	E, L L	KA K	direction and speed outputs requires external logic		
GEAR-TOOTH/RING MAGNET (DUAL ELEMENT) HALL-EFFECT SENSORS See also, Adaptive Threshold Sensors (modules containg sensor and magnet)								
Partial Part Number	Operate Point (G) Ove	Release Point (G) r Oper. Voltage	Hysteresis (G) e & Temp. Ra	Change in Trip Point (G) inge	Oper. Temp.	Package	Comments	
A3056x A3058x UGS3059 UGx3060 A3064L	<150 <250 10 to 100 5 to 35 0 to 27.5	>-150 >-250 -100 to -10 -35 to -5 -12.5 to 7.5	15 to 90 150 to 250 Typ130 Typ 30 5 to 35	<±75 <±50 — —	E, L E, L S, K S, K L	U U KA KA KA	zero-speed zero-speed >0.2 Hz >0.2 Hz >0.2 Hz >0.2 Hz	

Notes: 1) Typical data is at  $T_A = +25^{\circ}C$  and nominal operating voltage.

2) "x" = Operating Temperature Range [suffix letter or (prefix)]: S (UGN) =  $-20^{\circ}$ C to  $+85^{\circ}$ C, E =  $-40^{\circ}$ C to  $+85^{\circ}$ C, J =  $-40^{\circ}$ C to  $+115^{\circ}$ C, K (UGS) =  $-40^{\circ}$ C to  $+125^{\circ}$ C, L (UGL) =  $-40^{\circ}$ C to  $+150^{\circ}$ C.

*The products described herein are manufactured under one or more of the following U.S. patents: 5,045,920; 5,264,783; 5,442,283; 5,389,889; 5,581,179; 5,517,112; 5,619,137; 5,621,319; 5,650,719; 5,686,894; 5,694,038; 5,729,130; 5,917,320; and other patents pending.* 

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